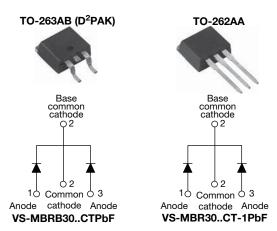


www.vishay.com

Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 15 A



PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	30 A
V_{R}	35 V, 45 V
V _F at I _F	0.6 V
I _{RM} max.	100 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	10.0 mJ

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Center tap D2PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform (per device)	30	Δ.		
I _{FRM}	T _C = 123 °C (per leg)	30	A		
V _{RRM}		35, 45	V		
I _{FSM}	t _p = 5 μs sine	1020	A		
V _F	20 A _{pk} , T _J = 125 °C	0.6	V		
TJ	Range	-65 to +150	°C		

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-MBRB3035CTPbF VS-MBRB3045CTPbF VS-MBRB3045CT-1PbF VS-MBR3045CT-1PbF UNITS					
Maximum DC reverse voltage	V_{R}	35	45	V	
Maximum working peak reverse voltage	V_{RWM}	33	45	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TI	EST CONDITIONS	VALUES	UNITS
Maximum average per leg	I	T 122 °C rated	V-	15	
forward current per device	I _{F(AV)}	$T_C = 123 ^{\circ}\text{C}$, rated V_R		30	
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 123 °C 30			
Non-repetitive peak surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	condition 1020	
Non-repetitive peak surge current	I _{FSM}	Surge applied at rated load conditions half wave, single phase, 60 Hz		200	
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 5 \text{mH}$		mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying I Frequency limited	inearly to zero in 1 μ s by T _J maximum V _A = 1.5 x V _R typical	2	Α

Revision: 18-Oct-16 1 Document Number: 94310



www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		
		30 A	T _J = 25 °C	0.76	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T _{.1} = 125 °C	0.6	V
		30 A	1j = 125 C	0.72	
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	1	- mA
reverse current		T _J = 125 °C	hated DC voltage	100	
Threshold voltage	V _{F(TO)}	$T_{.l} = T_{.l}$ maximum		0.29	V
Forward slope resistance	r _t	IJ = IJ MAXIMUM		13.6	mΩ
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		800	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECI	HANICAL	SPECIFIC	ATIONS			
PARAMETER		SYMBOL	IBOL TEST CONDITIONS		UNITS	
Maximum junction tempe	erature range	T_J		-65 to +150	°C	
Maximum storage tempe	rature range	T _{Stg}		-65 to +175	-0	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	1.5		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	50		
Aitil-t				2	g	
Approximate weight				0.07	OZ.	
Mounting torque minimum maximum			No. 1 le featail the control	6 (5)	kgf · cm	
			Non-lubricated threads	12 (10)	(lbf · in)	
Marking device			Case style D ² PAK	MBRB3	3045CT	
			Case style TO-262	MBR30	45CT-1	





www.vishay.com

Vishay Semiconductors

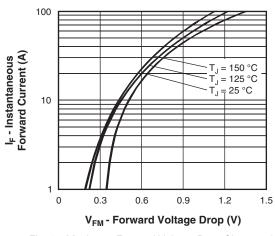


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

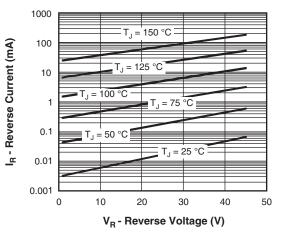


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

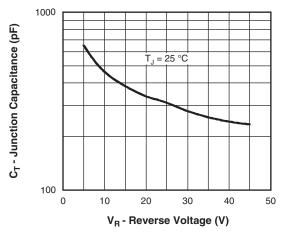


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

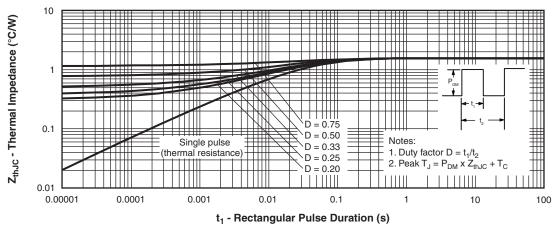


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



www.vishay.com

Vishay Semiconductors

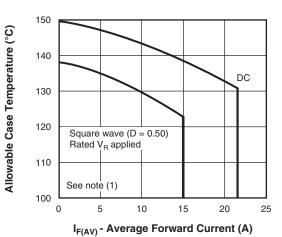


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

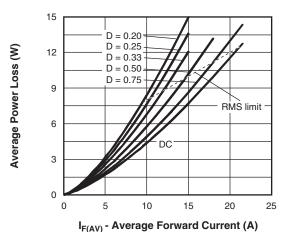


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

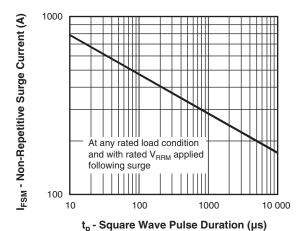


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

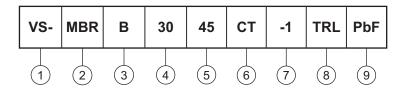
Note



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Essential part number
- 3 • B = D²PAK **7** None
 - None = TO-262 7 = -1
- Current rating (30 = 30 A)
- 5 Voltage ratings 35 = 35 V 45 = 45 V
- 6 CT = essential part number
- 7 • None = D²PAK **3** = B
 - -1 = TO-262 3 None
- 8 • None = tube (50 pieces)
 - TRL = tape and reel (left oriented for D²PAK only)
 - TRR = tape and reel (right oriented for D²PAK only)
- 9 • PbF = lead (Pb)-free (for TO-262 and D²PAK tube)
 - P = lead (Pb)-free (for D²PAK TRR and TRL)

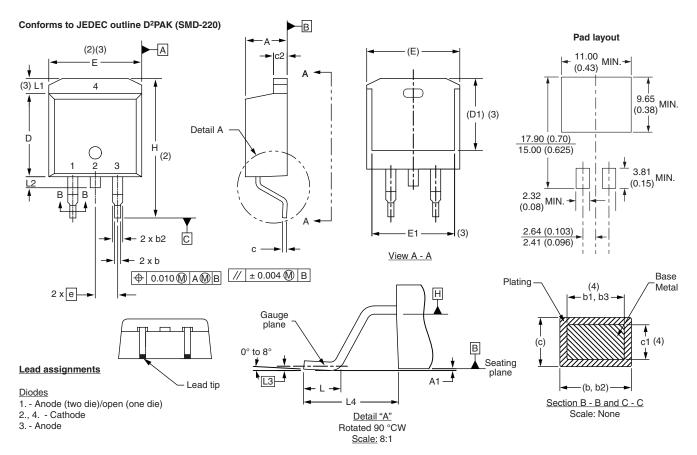
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			



Vishay Semiconductors

D²PAK, TO-262

DIMENSIONS - D²PAK in millimeters and inches



	1		1			
SYMBOL	MILLIN	MILLIMETERS		INCHES		
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

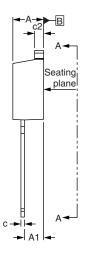
Document Number: 95014 Revision: 31-Mar-09

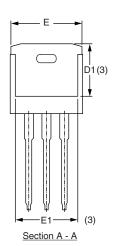
Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches





⊕ 0.010 **M** A **M** B

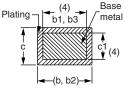
Lead assignments



Diodes

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	D BSC		
L	13.46	14.10	0.530	0.555		
L1	=	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2017 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED